# BLF10M6135; BLF10M6LS135

**Power LDMOS transistor** 

**AMPLEON** 

Rev. 2 — 1 September 2015

Product data sheet

## 1. Product profile

### 1.1 General description

135 W LDMOS power transistor for industrial applications at frequencies from 700 MHz to 1000 MHz.

#### Table 1. Typical performance

Typical RF performance at  $T_{case} = 25$  °C in a class-AB production test circuit.

Test signal	f	V <sub>DS</sub>	P <sub>L(AV)</sub>	G <sub>p</sub>	$\eta_D$	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	869 to 894	28	26.5	21.0	28.0	_39 <mark>[1]</mark>

<sup>[1]</sup> Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7.5 dB at 0.01 % probability on CCDF per carrier; carrier spacing 5 MHz.

#### 1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Enhanced ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (700 MHz to 1000 MHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding restriction of hazardous substances (RoHS)

### 1.3 Applications

■ RF power amplifiers for ISM applications in the 700 MHz to 1000 MHz frequency range

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLF10M6135	(SOT502A)		
1	drain		
2	gate	1	1 
3	source [1]	2 3	2 3 sym112
BLF10M6LS1	35 (SOT502B)		
1	drain		
2	gate	1	1 
3	source [1]	2 3	2 3 3 sym112

<sup>[1]</sup> Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BLF10M6135	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT502A		
BLF10M6LS135	-	earless flanged ceramic package; 2 leads	SOT502B		

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS}$	gate-source voltage		-0.5	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

<sup>[1]</sup> Continuous use at maximum temperature will affect reliability.

### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Туре	Тур	Unit
R <sub>th(j-case)</sub>		$T_{case}$ = 80 °C; $P_{L}$ = 25 W	BLF10M6135	0.68	K/W
	junction to case		BLF10M6LS135	0.56	K/W

BLF10M6135\_BLF10M6LS135#2

All information provided in this document is subject to legal disclaimers.

© Ampleon The Netherlands B.V. 2015. All rights reserved.

### 6. Characteristics

#### Table 6. DC characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.8 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS}$ = 10 V; $I_{D}$ = 180 mA	1.4	1.9	2.4	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS}$ = 28 V; $I_{D}$ = 950 mA	1.6	2.1	2.6	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 28 V	-	-	3	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	24	32	-	А
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V	-	-	300	nA
g <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 9 A	7	13	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 6.3 \text{ A}$	-	0.1	-	Ω

#### Table 7. AC characteristics

 $T_i = 25 \, ^{\circ}\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>rs</sub>	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}; f = 1 \text{ MHz}$	-	2.0	-	pF

#### Table 8. RF characteristics

Test signal: 2-carrier W-CDMA; PAR 7.5 dB at 0.01 % probability on CCDF; 3GPP test model 1; 1-64 DPCH;  $f_1$  = 871.5 MHz;  $f_2$  = 876.5 MHz;  $f_3$  = 886.5 MHz;  $f_4$  = 891.5 MHz; RF performance at  $V_{DS}$  = 28 V;  $I_{Dq}$  = 950 mA;  $T_{case}$  = 25 °C; unless otherwise specified; in a class-AB production test circuit.

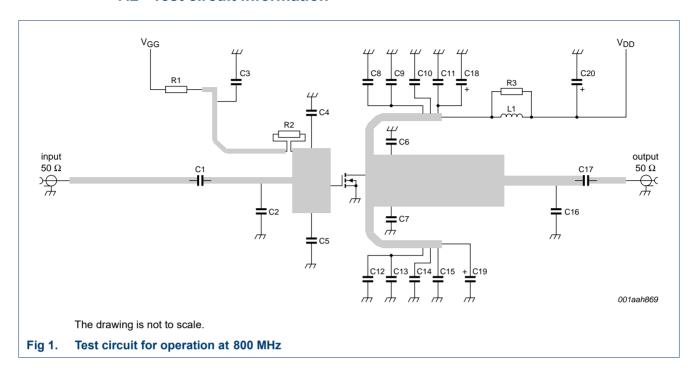
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G <sub>p</sub>	power gain	P <sub>L(AV)</sub> = 26.5 W	20.0	21.0	-	dB
RLin	input return loss	P <sub>L(AV)</sub> = 26.5 W	-	-10.0	-6.5	dB
$\eta_{D}$	drain efficiency	P <sub>L(AV)</sub> = 26.5 W	26.0	28.0	-	%
ACPR	adjacent channel power ratio	P <sub>L(AV)</sub> = 26.5 W	-	-39	-36.5	dBc

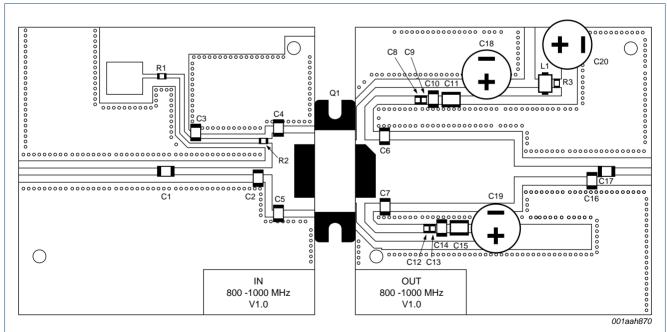
### 7. Test information

### 7.1 Ruggedness in class-AB operation

The BLF10M6135 and BLF10M6LS135 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS} = 28 \text{ V}$ ;  $I_{Dq} = 950 \text{ mA}$ ;  $P_L = 135 \text{ W}$ ; f = 894 MHz.

### 7.2 Test circuit information





The striplines are on a double copper-clad Taconic RF35 Printed-Circuit Board (PCB) with  $\epsilon_r$  = 3.5 and thickness = 0.76 mm. See Table 9 for list of components.

The drawing is not to scale.

Fig 2. Component layout

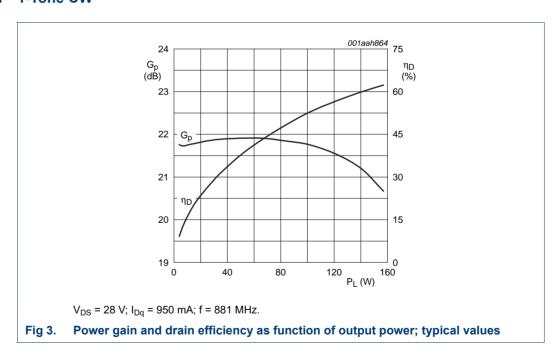
Table 9. List of components See Figure 1 and Figure 2.

Component	Description	Value		Remarks
C1, C3, C10, C14, C17	multilayer ceramic chip capacitor	68 pF	[1]	solder vertically
C2, C4, C5	multilayer ceramic chip capacitor	8.2 pF	[1]	solder vertically
C6, C7	multilayer ceramic chip capacitor	10 pF	[1]	solder vertically
C8, C9, C12, C13	electrolytic capacitor	100 nF		Vishay or capacitor of same quality
C11, C15	multilayer ceramic chip capacitor	4.7 μF, 50 V	[2]	
C16	multilayer ceramic chip capacitor	3.0 pF	[1]	solder vertically
C18, C19, C20	electrolytic capacitor	220 μF, 63 V		
L1	ferrite SMD bead			Ferroxcube BDS 3/3/4.6-4S2 or equivalent
Q1	BLF10M6135			
R1, R2, R3	SMD resistor	9.1 Ω, 0.1 W		

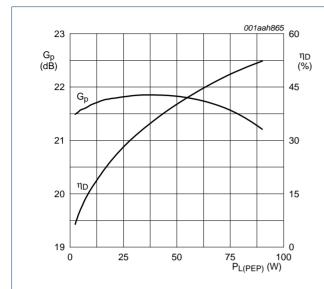
- [1] American Technical Ceramics type 100B or capacitor of same quality.
- [2] TDK or capacitor of same quality.

## 7.3 Graphical data

### 7.3.1 1-Tone CW

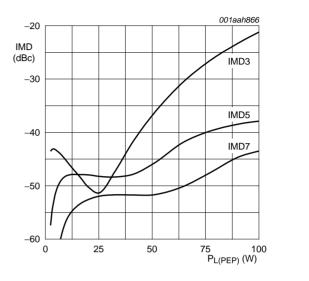


#### 7.3.2 2-Tone CW



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 950 mA; f = 881 MHz (± 100 kHz).

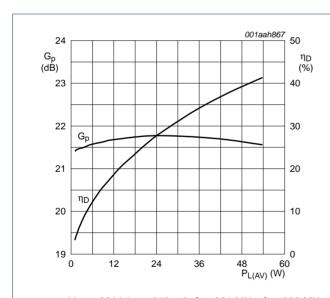
Fig 4. Power gain and drain efficiency as function of peak envelope power load power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 950 mA; f = 881 MHz (± 100 kHz).

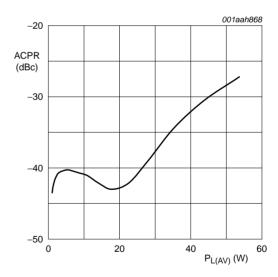
Fig 5. Intermodulation distortion as a function of peak envelope power load power; typical values

#### 7.3.3 2-Carrier W-CDMA



 $\rm V_{DS}$  = 28 V;  $\rm I_{Dq}$  = 950 mA;  $\rm f_1$  = 881 MHz;  $\rm f_2$  = 886 MHz; carrier spacing 5 MHz.

Fig 6. Power gain and drain efficiency as function of average output power; typical values



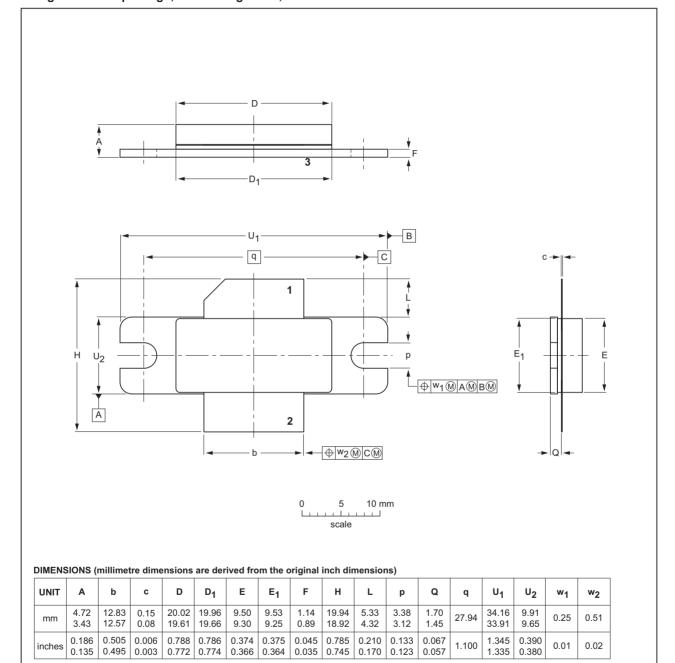
 $\rm V_{DS}$  = 28 V;  $\rm I_{Dq}$  = 950 mA;  $\rm f_1$  = 881 MHz;  $\rm f_2$  = 886 MHz; carrier spacing 5 MHz.

Fig 7. Adjacent power channel ratio as a function of average output power; typical values

## 8. Package outline

Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A

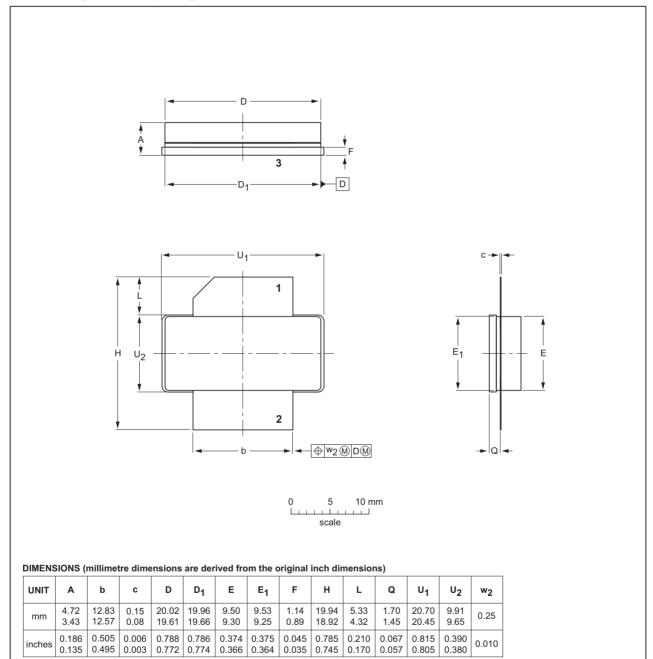


OUTLINE		REFERENCES			EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT502A						<del>-03-01-10-</del> 12-05-02	

Fig 8. Package outline SOT502A

#### Earless flanged ceramic package; 2 leads

SOT502B



OUTLINE		REFERENCES				ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT502B						<del>07-05-09</del> 12-05-02

Fig 9. Package outline SOT502B

## 9. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

## 10. Abbreviations

Table 10. Abbreviations

Acronym	Description	
3GPP	3rd Generation Partnership Project	
CCDF	Complementary Cumulative Distribution Function	
CW	Continuous Wave	
DPCH	Dedicated Physical CHannel	
ESD	ElectroStatic Discharge	
ISM	Industrial, Scientific and Medical	
LDMOS	Laterally Diffused Metal-Oxide Semiconductor	
PAR	Peak-to-Average Ratio	
SMD	Surface Mounted Device	
VSWR	Voltage Standing-Wave Ratio	
W-CDMA	Wideband Code Division Multiple Access	

## 11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF10M6135_BLF10M6LS135#2	20150901	Product data sheet		BLF10M6135_BLF10 M6LS135 v.1	
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>				
BLF10M6135_BLF10M6LS135 v.1	20140624	Product data sheet	-	-	

## 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

#### 12.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Ampleon sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Ampleon and its customer, unless Ampleon and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Ampleon product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### 12.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Ampleon does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Ampleon takes no responsibility for the content in this document if provided by an information source outside of Ampleon.

In no event shall Ampleon be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Ampleon' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Ampleon.

Right to make changes — Ampleon reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — Ampleon products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an

Ampleon product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Ampleon and its suppliers accept no liability for inclusion and/or use of Ampleon products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Ampleon makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Ampleon products, and Ampleon accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Ampleon product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Ampleon does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Ampleon products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Ampleon does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Ampleon products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.ampleon.com/terms">http://www.ampleon.com/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Ampleon hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Ampleon products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

BLF10M6135 BLF10M6LS135#2

## BLF10M6135; BLF10M6LS135

**Power LDMOS transistor** 

Non-automotive qualified products — Unless this data sheet expressly states that this specific Ampleon product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Ampleon accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Ampleon' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Ampleon' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Ampleon for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Ampleon' standard warranty and Ampleon' product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### 12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own trademarks.

### 13. Contact information

For more information, please visit: http://www.ampleon.com

For sales office addresses, please visit: http://www.ampleon.com/sales

## **AMPLEON**

# BLF10M6135; BLF10M6LS135

**Power LDMOS transistor** 

## 14. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
2	Pinning information
3	Ordering information
4	Limiting values
5	Thermal characteristics
6	Characteristics
7	Test information
7.1	Ruggedness in class-AB operation
7.2	Test circuit information
7.3	Graphical data
7.3.1	1-Tone CW
7.3.2	2-Tone CW
7.3.3	2-Carrier W-CDMA
8	Package outline
9	Handling information
10	Abbreviations
11	Revision history 9
12	Legal information
12.1	Data sheet status
12.2	Definitions
12.3	Disclaimers
12.4	Trademarks1
13	Contact information
11	Contents 11

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

## **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

NXP:

BLF10M6135U BLF10M6LS135U